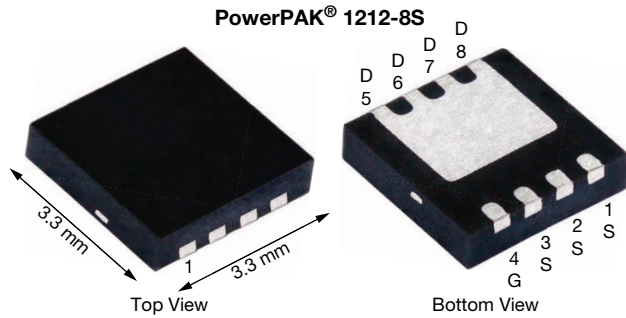


P-Channel 60 V (D-S) MOSFET



PRODUCT SUMMARY	
V_{DS} (V)	-60
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -10$ V	0.024
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5$ V	0.046
Q_g typ. (nC)	10.1
I_D (A)	-36.2
Configuration	Single

ORDERING INFORMATION	
Package	PowerPAK 1212-8S
Lead (Pb)-free and halogen-free	SiSS5623DN-T1-GE3

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-source voltage	V_{DS}	-60	V	
Gate-source voltage	V_{GS}	± 20		
Continuous drain current ($T_J = 150$ °C)	I_D	$T_C = 25$ °C	-36.3	A
		$T_C = 70$ °C	-29.0	
		$T_A = 25$ °C	-10.5 ^{b, c}	
		$T_A = 70$ °C	-8.4 ^{b, c}	
Pulsed drain current ($t = 100$ μ s)	I_{DM}	-80		
Continuous source-drain diode current	I_S	$T_C = 25$ °C	-47.3	
		$T_A = 25$ °C	-4.0 ^{b, c}	
Single pulse avalanche current	I_{AS}	-20		
Single pulse avalanche energy	E_{AS}	20	mJ	
Maximum power dissipation	P_D	$T_C = 25$ °C	56.8	W
		$T_C = 70$ °C	36.3	
		$T_A = 25$ °C	4.8 ^{b, c}	
		$T_A = 70$ °C	3.0 ^{b, c}	
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +150	°C	
Soldering recommendations (peak temperature) ^c		260		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^b	$t \leq 10$ s	R_{thJA}	21	26	°C/W
Maximum junction-to-case (drain)	Steady state	R_{thJC}	1.8	2.2	

Notes

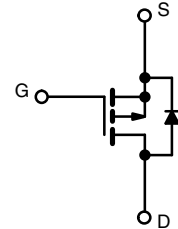
- $T_C = 25$ °C
- Surface mounted on 1" x 1" FR4 board
- $t = 10$ s
- See solder profile (www.vishay.com/doc?73257). The PowerPAK 1212-8S is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
- Maximum under steady state conditions is 70 °C/W

FEATURES

- New generation p-channel power MOSFET
- 100 % R_g and UIS tested
- Ultra low R_{DS} x Q_g FOM product
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE
APPLICATIONS

- Battery management
- Load switch
- Motor drive control



P-Channel MOSFET



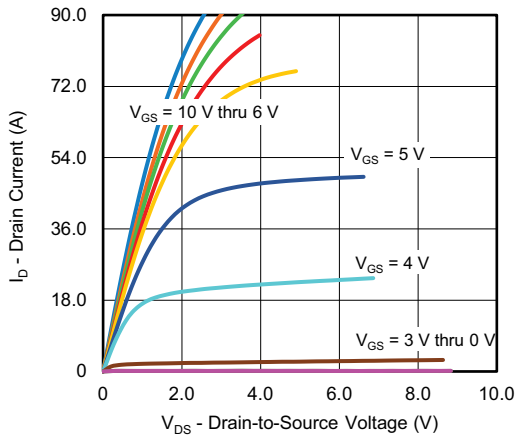
SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0\text{ V}$, $I_D = -250\text{ }\mu\text{A}$	-60	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	$I_D = -10\text{ mA}$	-	-26	-	mV/ $^\circ\text{C}$
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$	$I_D = -250\text{ }\mu\text{A}$	-	4.8	-	
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250\text{ }\mu\text{A}$	-1.4	-	-2.6	V
Gate-source leakage	I_{GSS}	$V_{DS} = 0\text{ V}$, $V_{GS} = \pm 20\text{ V}$	-	-	100	nA
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -60\text{ V}$, $V_{GS} = 0\text{ V}$	-	-	-10	μA
		$V_{DS} = -60\text{ V}$, $V_{GS} = 0\text{ V}$, $T_J = 70\text{ }^\circ\text{C}$	-	-	-50	
Drain-source on-state resistance ^a	$R_{DS(on)}$	$V_{GS} = -10\text{ V}$, $I_D = -10\text{ A}$	-	0.0195	0.024	Ω
		$V_{GS} = -4.5\text{ V}$, $I_D = -10\text{ A}$	-	0.0375	0.046	
Forward transconductance ^a	g_{fs}	$V_{DS} = -15\text{ V}$, $I_D = -15\text{ A}$	-	23	-	S
Dynamic ^b						
Input capacitance	C_{iss}	$V_{DS} = -30\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	-	1575	-	pF
Output capacitance	C_{oss}		-	800	-	
Reverse transfer capacitance	C_{rss}		-	36	-	
Total gate charge	Q_g	$V_{DS} = -30\text{ V}$, $V_{GS} = -10\text{ V}$, $I_D = -10\text{ A}$	-	21.8	33	nC
		$V_{DS} = -30\text{ V}$, $V_{GS} = -4.5\text{ V}$, $I_D = -10\text{ A}$	-	10.1	15.5	
Gate-source charge	Q_{gs}	$V_{DS} = -30\text{ V}$, $V_{GS} = -4.5\text{ V}$, $I_D = -10\text{ A}$	-	6.4	-	nC
Gate-drain charge	Q_{gd}		-	2.7	-	
Gate resistance	R_g		$f = 1\text{ MHz}$	0.4	1.0	
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -30\text{ V}$, $R_L = 3\text{ }\Omega$, $I_D \equiv -10\text{ A}$, $V_{GEN} = -10\text{ V}$, $R_g = 1\text{ }\Omega$	-	12	24	ns
Rise time	t_r		-	5	10	
Turn-off delay time	$t_{d(off)}$		-	21	42	
Fall time	t_f		-	5	10	
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -30\text{ V}$, $R_L = 3\text{ }\Omega$, $I_D \equiv -10\text{ A}$, $V_{GEN} = -4.5\text{ V}$, $R_g = 1\text{ }\Omega$	-	24	48	
Rise time	t_r		-	181	360	
Turn-off delay time	$t_{d(off)}$		-	14	28	
Fall time	t_f		-	9	18	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I_S	$T_C = 25\text{ }^\circ\text{C}$	-	-	-47.3	A
Pulse diode forward current	I_{SM}		-	-	-80	
Body diode voltage	V_{SD}	$I_S = -5\text{ A}$, $V_{GS} = 0\text{ V}$	-	-0.81	-1.2	V
Body diode reverse recovery time	t_{rr}	$I_F = -10\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$, $T_J = 25\text{ }^\circ\text{C}$	-	42	84	ns
Body diode reverse recovery charge	Q_{rr}		-	37	74	nC
Reverse recovery fall time	t_a		-	15	-	ns
Reverse recovery rise time	t_b		-	27	-	

Notes

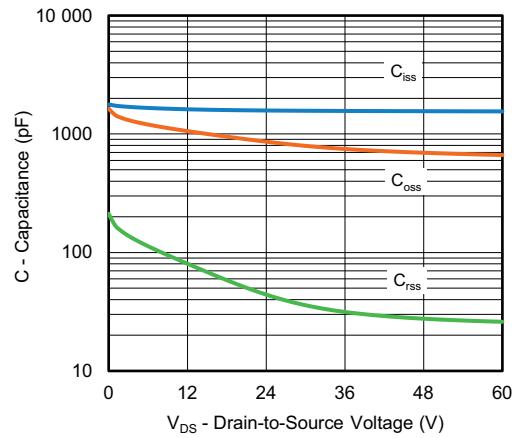
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

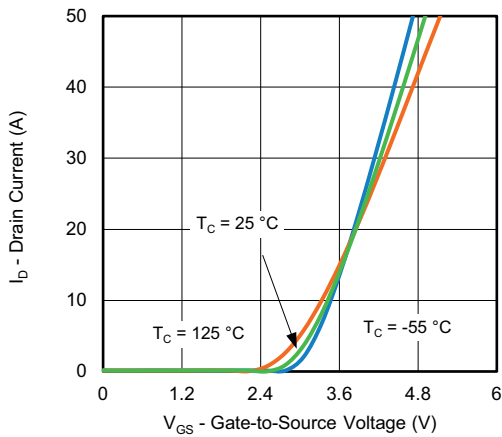
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



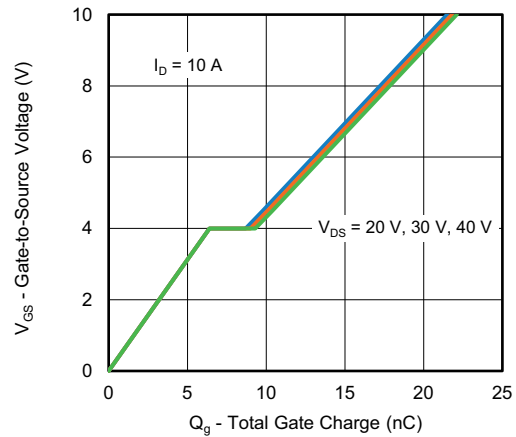
Output Characteristics



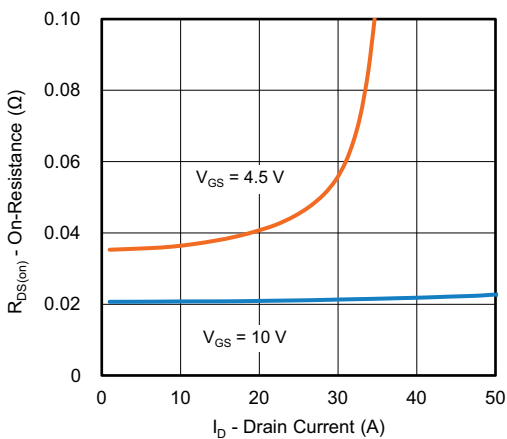
Transfer Characteristics



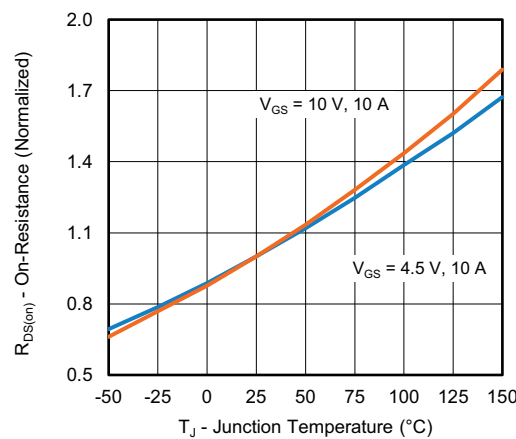
On-Resistance vs. Drain Current and Gate Voltage



Capacitance



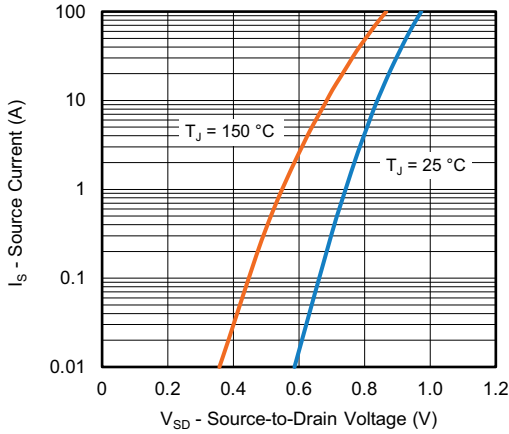
Gate Charge



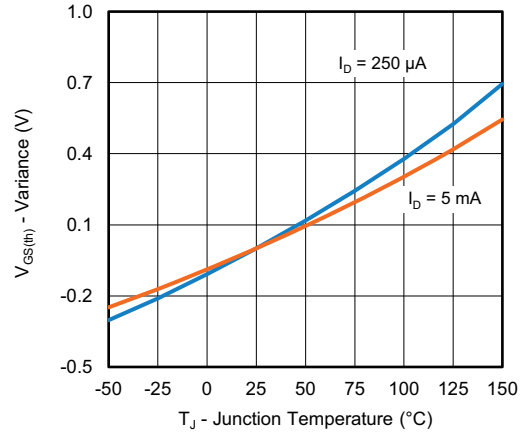
On-Resistance vs. Junction Temperature



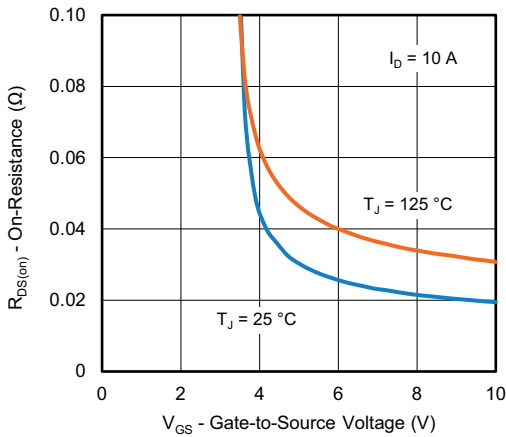
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



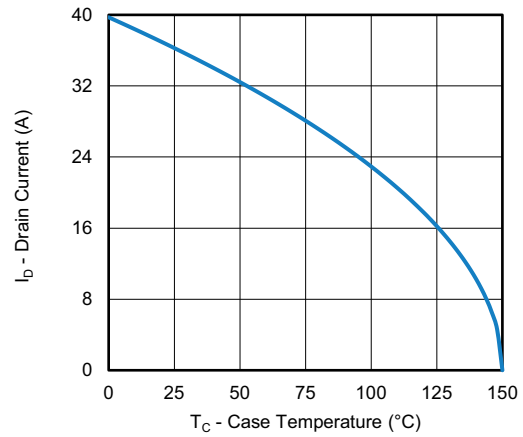
Source-Drain Diode Forward Voltage



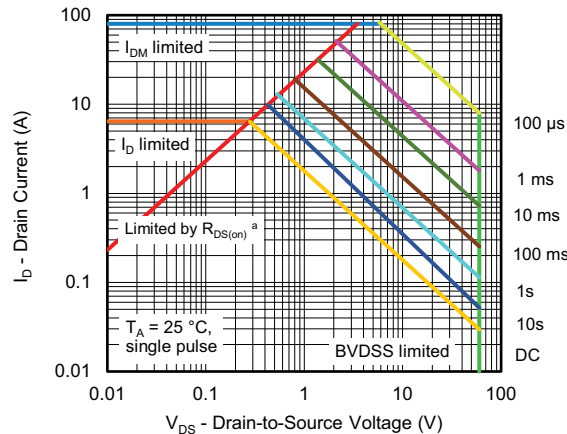
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power, Junction-to-Ambient



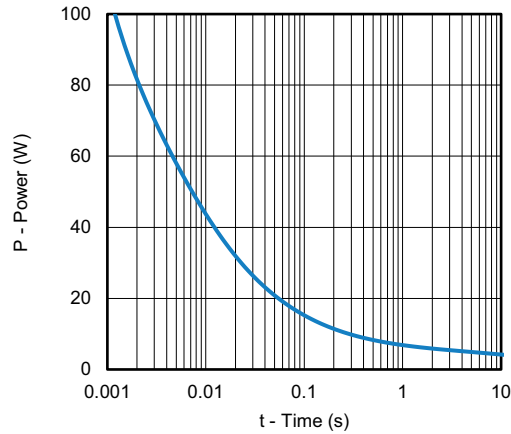
Safe Operating Area, Junction-to-Ambient

Note

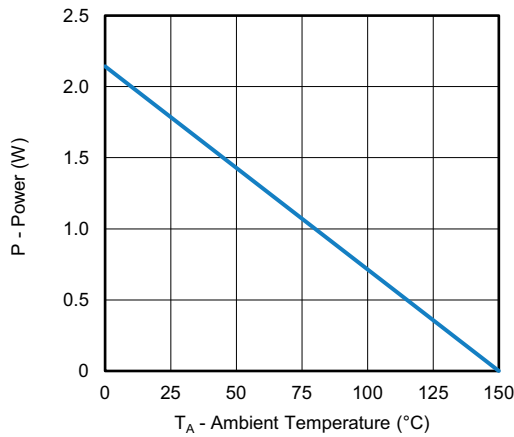
a. $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified



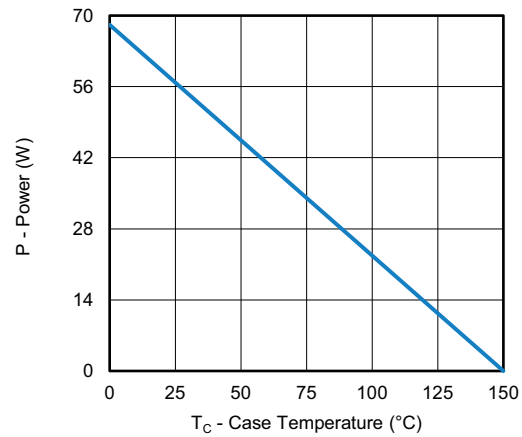
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating ^a



Single Pulse Power, Junction-to-Ambient



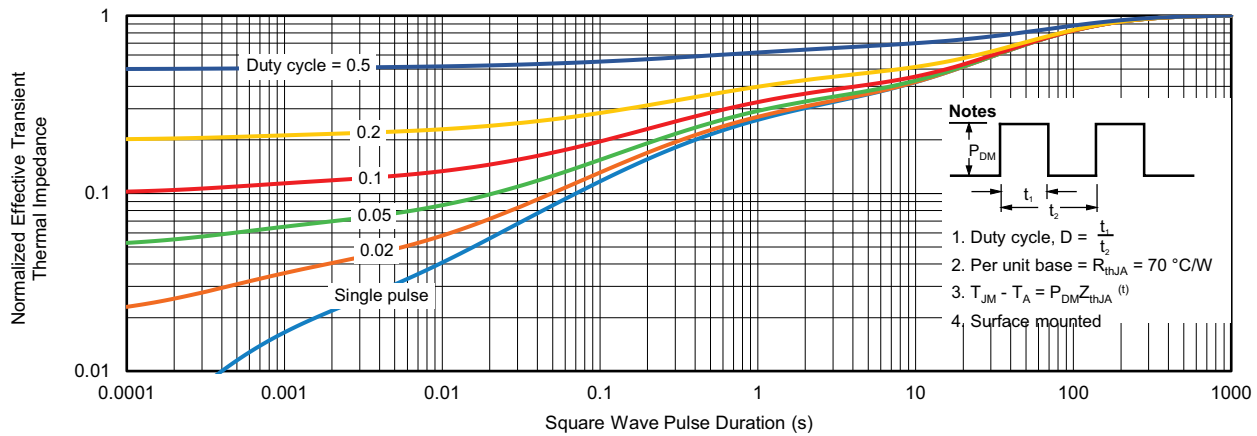
Power, Junction-to-Case

Note

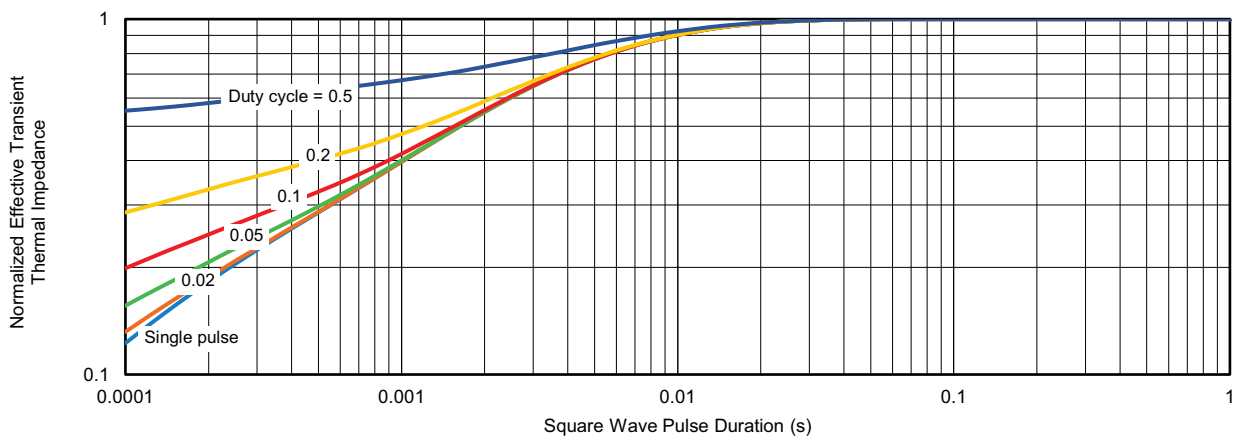
a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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